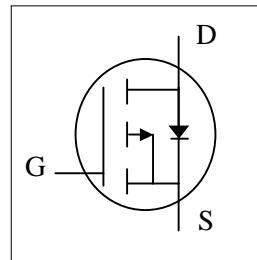




- ▼ Simple Drive Requirement
- ▼ Small Size & Lower Profile
- ▼ RoHS Compliant & Halogen-Free

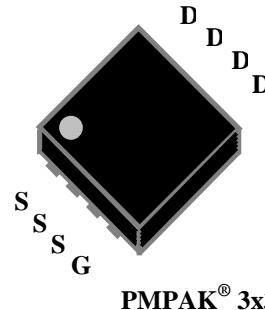


BV_{DSS}	-30V
$R_{DS(ON)}$	13mΩ
I_D	-12.8A

Description

Advanced Power MOSFETs from APEC provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The PMPAK® 3x3 package is special for DC-DC converters application and lower 1.0mm profile with backside heat sink.



PMPAK® 3x3

Absolute Maximum Ratings@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D @ T_A = 25^\circ\text{C}$	Drain Current ³ , $V_{GS} @ 10\text{V}$	-12.8	A
$I_D @ T_A = 70^\circ\text{C}$	Drain Current ³ , $V_{GS} @ 10\text{V}$	-10.3	A
I_{DM}	Pulsed Drain Current ¹	-50	A
$P_D @ T_A = 25^\circ\text{C}$	Total Power Dissipation	3.13	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Value	Unit
R_{thj-c}	Maximum Thermal Resistance, Junction-case	5	°C/W
R_{thj-a}	Maximum Thermal Resistance, Junction-ambient ³	40	°C/W



Electrical Characteristics@ $T_j=25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance ²	$V_{GS}=-10V, I_D=-10A$	-	10.1	13	$m\Omega$
		$V_{GS}=-4.5V, I_D=-6A$	-	15.2	20	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.5	-3	V
g_f	Forward Transconductance	$V_{DS}=-10V, I_D=-10A$	-	22	-	S
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=-24V, V_{GS}=0V$	-	-	-10	μA
I_{GSS}	Gate-Source Leakage	$V_{GS}=+20V, V_{DS}=0V$	-	-	± 100	nA
Q_g	Total Gate Charge ²	$I_D=-10A$	-	24	38	nC
Q_{gs}	Gate-Source Charge	$V_{DS}=-15V$	-	6.5	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	$V_{GS}=-4.5V$	-	10	-	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{DS}=-15V$	-	11	-	ns
t_r	Rise Time	$I_D=-1A$	-	9.5	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=3.3\Omega$	-	80	-	ns
t_f	Fall Time	$V_{GS}=-10V$	-	33	-	ns
C_{iss}	Input Capacitance	$V_{GS}=0V$	-	2960	4735	pF
C_{oss}	Output Capacitance	$V_{DS}=-15V$	-	305	-	pF
C_{rss}	Reverse Transfer Capacitance	$f=1.0MHz$	-	265	-	pF
R_g	Gate Resistance	$f=1.0MHz$	-	6.2	12.4	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_{SD}	Forward On Voltage ²	$I_S=-2.9A, V_{GS}=0V$	-	-	-1.2	V
t_{rr}	Reverse Recovery Time	$I_S=-10A, V_{GS}=0V,$	-	20	-	ns
Q_{rr}	Reverse Recovery Charge	$dI/dt=100A/\mu s$	-	6	-	nC

Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in² 2oz copper pad of FR4 board, t <10sec ; 210°C/W when mounted on min. copper pad.

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

APEC DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

APEC RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.

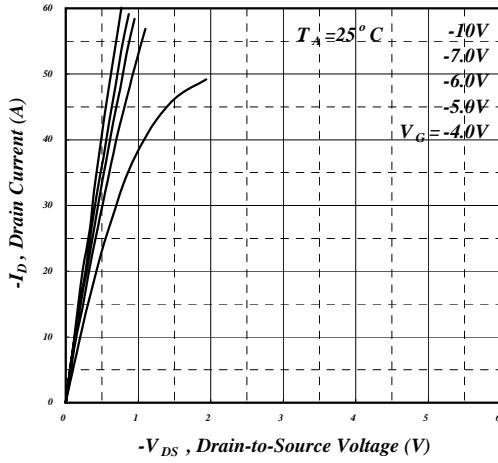


Fig 1. Typical Output Characteristics

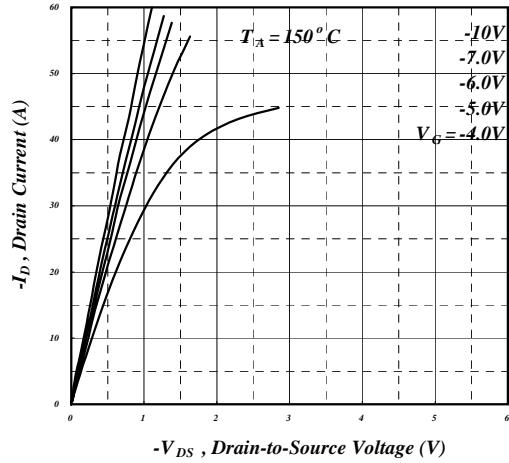


Fig 2. Typical Output Characteristics

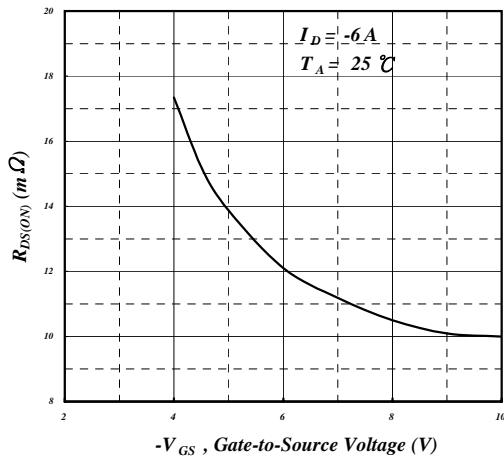


Fig 3. On-Resistance v.s. Gate Voltage

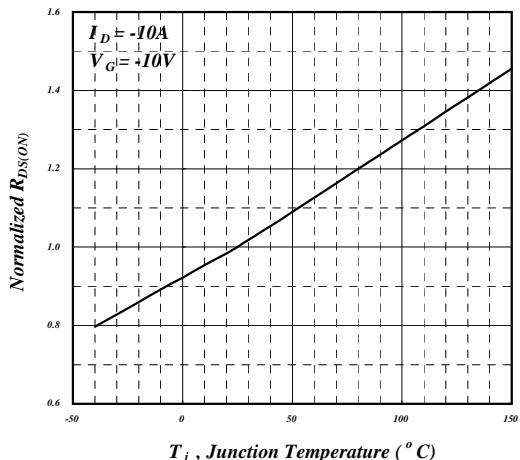


Fig 4. Normalized On-Resistance v.s. Junction Temperature

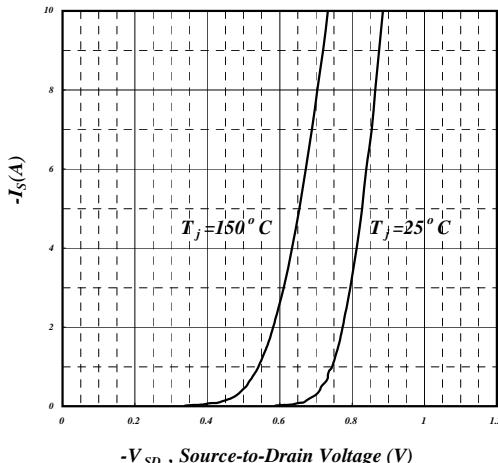


Fig 5. Forward Characteristic of Reverse Diode

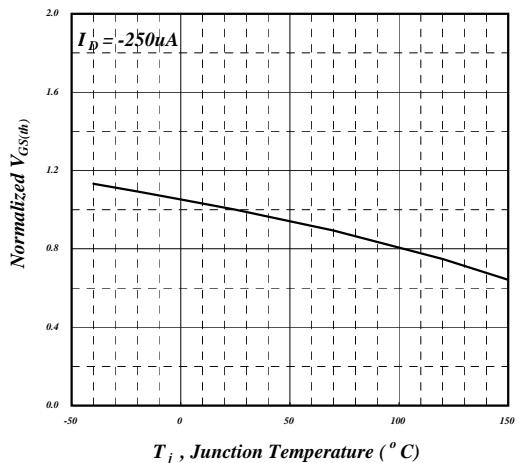


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

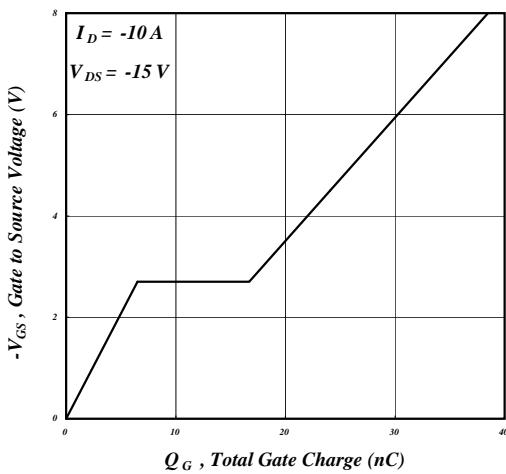


Fig 7. Gate Charge Characteristics

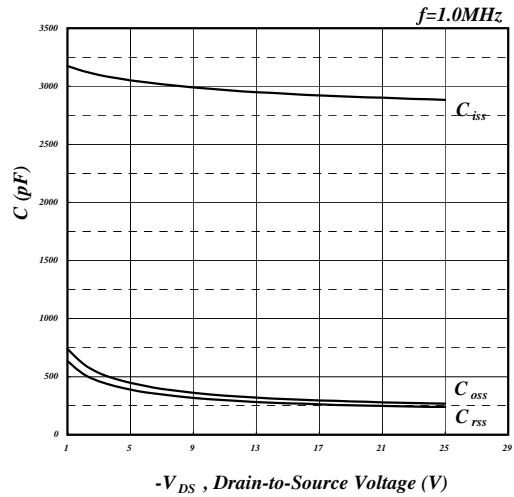


Fig 8. Typical Capacitance Characteristics

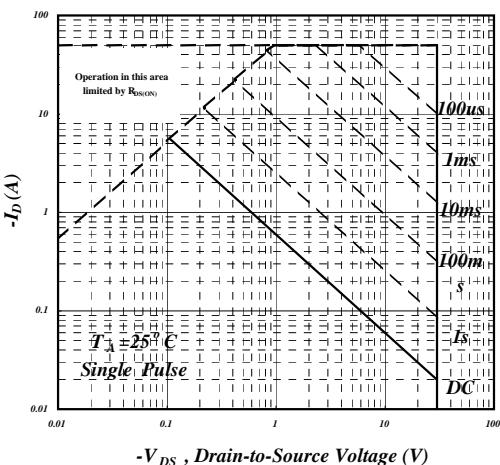


Fig 9. Maximum Safe Operating Area

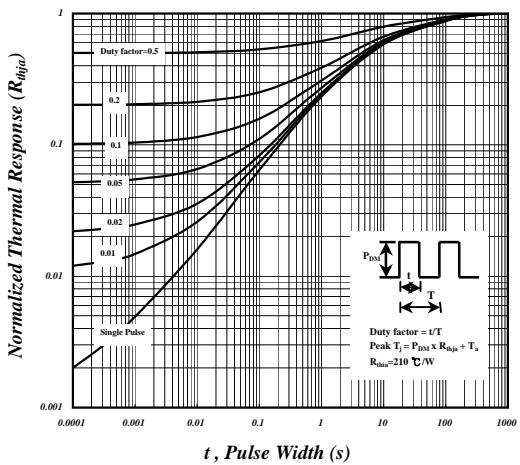


Fig 10. Effective Transient Thermal Impedance

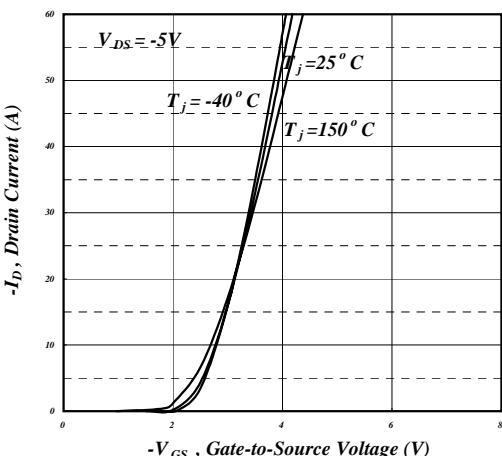


Fig 11. Transfer Characteristics

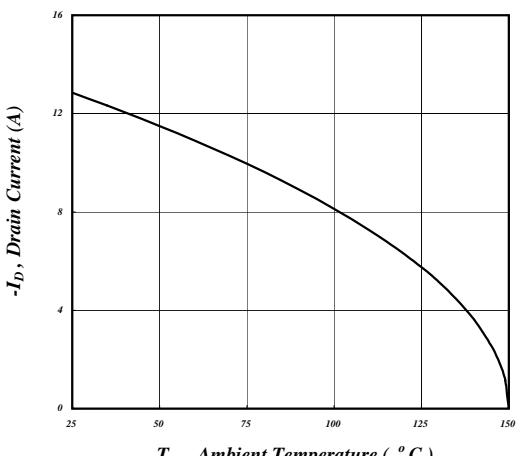
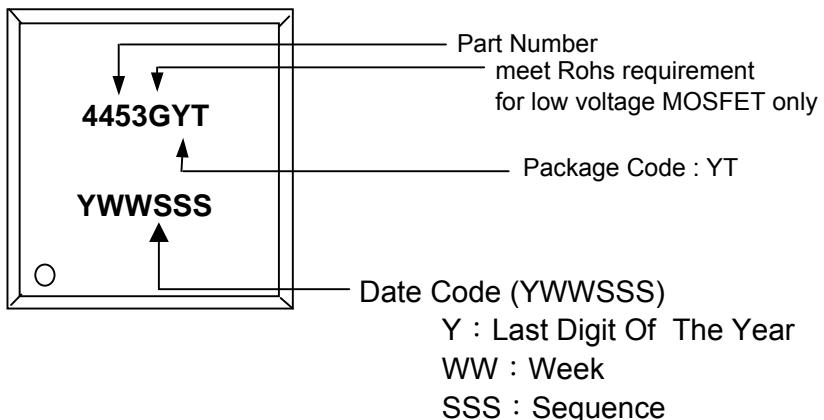


Fig 12. Drain Current v.s. Ambient Temperature

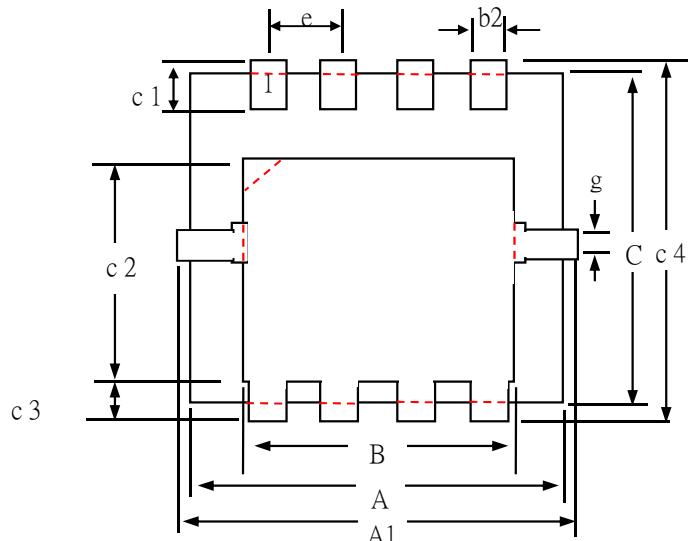


MARKING INFORMATION

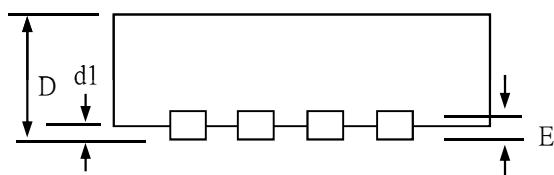




Package Outline : PMPAK 3x3



BOTTOM VIEW



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	2.90	3.10	3.40
B	2.20	2.45	2.80
e	0.60	0.65	0.70
b2	0.20	0.30	0.40
C	2.90	3.10	3.40
c1	0.10	0.30	0.50
c2	1.20	1.70	2.20
c3	0.10	0.38	0.65
D	0.65	0.80	1.05
d1	0.00	0.10	0.20
E	0.10	0.18	0.25
A1	2.900	3.30	3.600
c4	2.900	3.30	3.600
g	0.20 (ref)		

1. All Dimension Are In Millimeters.

2. Dimension Does Not Include Mold Protrusions.

3. Thermal PAD and Pin contour is for reference, it may has little difference by option.



PMPAK3X3 FOOTPRINT :

